DSC7501

Silicon NPN epitaxial planar type

For low frequency amplification DSC2501 in MiniP3 type package

Features

- \bullet Low collector-emitter saturation voltage $V_{\text{CE}(\text{sat})}$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

Packaging

DSC7501×0L Embossed type (Thermo-compression sealing): 1000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	25	V
Collector-emitter voltage (Base open)	V _{CEO}	20	V
Emitter-base voltage (Collector open)	V _{EBO}	12	V
Collector current	I _C	0.5	А
Peak collector current	I _{CP}	1	А
Collector power dissipation	P _C	1	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Note) Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion

Absolute maximum rating without heat sink for $P_{\rm C}~{\rm is}~~0.5~{\rm W}$

Package

- Code
- MiniP3-F2-B
 - Package dimension clicks here. $\!\rightarrow$
- Pin Name
 - 1. Base
 - 2. Collector
 - 3. Emitter

Marking Symbol: E3

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	25			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	20			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	12			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 25 \text{ V}, I_E = 0$			100	nA
Forward current transfer ratio *2	h _{FE}	$V_{CE} = 2 V, I_C = 0.5 A$	200		800	
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = 0.5 \text{A}, I_{\rm B} = 20 \text{mA}$		0.18	0.40	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = 0.5 \text{A}, I_{\rm B} = 50 \text{mA}$			1.2	V
Transition frequency	f _T	$V_{CE} = 10 \text{ V}, I_C = 50 \text{ mA}$		150		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6		pF
ON resistance *3	R _{on}			1.0		Ω

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

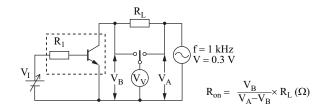
2. *1: Pulse measurement

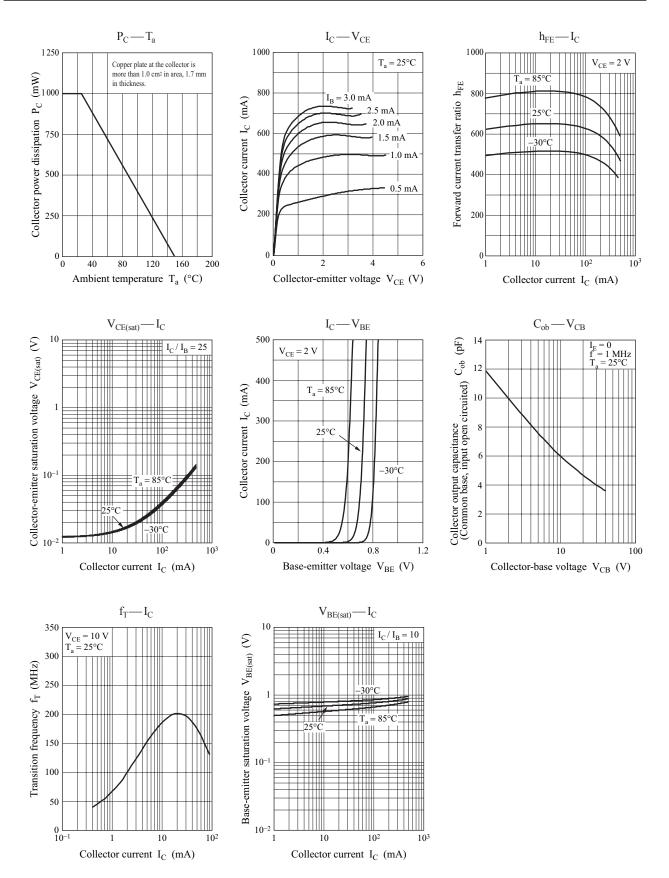
*2: Rank classification

Code	R	S	Т	0
Rank	R	S	Т	No-rank
h _{FE}	200 to 350	300 to 500	400 to 800	200 to 800
Marking Symbol	E3R	E3S	E3T	E3

Product of no-rank is not classified and have no marking symbol for rank.

*3: Ron measurement circuit





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